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## FAIRCHILD

SEMICONDUCTOR*

## 2N6517

## NPN Epitaxial Silicon Transistor

## Features

- High Voltage Transistor
- Collector Dissipation: $\mathrm{P}_{\mathrm{C}}(\mathrm{max})=625 \mathrm{~mW}$
- Complement to 2N6520
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



## Absolute Maximum Ratings $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter |  | Value | Units |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {CBO }}$ | Collector-Base Voltage | $\begin{aligned} & \text { 2N6517 } \\ & \text { 2N6517C } \end{aligned}$ | $\begin{aligned} & 350 \\ & 400 \end{aligned}$ | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {CEO }}$ | Collector-Emitter Voltage | $\begin{aligned} & \hline \text { 2N6517 } \\ & \text { 2N6517C } \end{aligned}$ | $\begin{aligned} & \hline 350 \\ & 400 \end{aligned}$ | $\begin{aligned} & \hline \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{V}_{\text {EBO }}$ | Emitter-Base Voltage |  | 6 | V |
| $\mathrm{I}_{\mathrm{C}}$ | Collector Current |  | 500 | mA |
| $\mathrm{P}_{\mathrm{C}}$ | Collector Power Dissipation |  | 625 | mW |
| $\mathrm{T}_{J}$ | Junction Temperature |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature |  | -55~150 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Conditions | Min. | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{BV}_{\text {CBO }}$ | Collector-Base Breakdown Voltage 2N6517 2N6517C | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{E}}=0 \\ & \mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{E}}=0 \end{aligned}$ | $\begin{aligned} & 350 \\ & 400 \end{aligned}$ |  | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\mathrm{BV}_{\text {CEO }}$ | Collector-Emitter Breakdown Voltage * 2N6517 2N6517C | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=0 \\ & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=0 \end{aligned}$ | $\begin{aligned} & 350 \\ & 400 \end{aligned}$ |  | $\begin{aligned} & \text { V } \\ & \text { V } \end{aligned}$ |
| $\mathrm{BV}_{\text {EBO }}$ | Emitter-Base Breakdown Voltage | $\mathrm{I}_{\mathrm{E}}=10 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{C}}=0$ | 6 |  | V |
| $\mathrm{I}_{\text {CBO }}$ | Collector Cut-off Current | $\mathrm{V}_{\mathrm{CB}}=250 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=0$ |  | 50 | nA |
| $\mathrm{I}_{\text {ebo }}$ | Emitter Cut-off Current | $\mathrm{V}_{\mathrm{EB}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0$ |  | 50 | nA |
| $\mathrm{h}_{\text {FE }}$ | DC Current Gain *  <br>  2N6517/2N6517C <br> 2N6517/2N6517C  <br> 2N6517/2N6517C  <br> 2N6517/2N6517C  <br> 2N6517/2N6517C  <br> 2N6517C  | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=30 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=100 \mathrm{~mA} \\ & \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=5 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & 20 \\ & 30 \\ & 30 \\ & 20 \\ & 15 \\ & 50 \end{aligned}$ | $\begin{aligned} & 200 \\ & 200 \\ & 200 \end{aligned}$ |  |

Electrical Characteristics (Continued) $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Conditions | Min. | Max. | Units |
| :---: | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CE}(\text { sat })}$ | Collector-Emitter Saturation Voltage | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=1 \mathrm{~mA}$ |  | 0.3 | V |
|  |  | $\mathrm{I}_{\mathrm{C}}=20 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=2 \mathrm{~mA}$ |  | 0.35 | V |
|  |  | $\mathrm{I}_{\mathrm{C}}=30 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=3 \mathrm{~mA}$ |  | 0.5 | V |
|  |  | $\mathrm{I}_{\mathrm{C}}=50 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=5 \mathrm{~mA}$ |  | 1 | V |
| $\mathrm{~V}_{\mathrm{BE}(\text { sat })}$ | Base-Emitter Saturation Voltage | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=1 \mathrm{~mA}$ |  | 0.75 | V |
|  |  | $\mathrm{I}_{\mathrm{C}}=20 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=2 \mathrm{~mA}$ | 0.85 | V |  |
|  |  | $\mathrm{I}_{\mathrm{C}}=30 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=3 \mathrm{~mA}$ |  | 0.9 | V |
| $\mathrm{C}_{\mathrm{ob}}$ | Output Capatitance | $\mathrm{V}_{\mathrm{CB}}=20 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1 \mathrm{MHz}$ |  | 6 | pF |
| $\mathrm{f}_{\mathrm{T}}$ | Current Gain Bandwidth Product $*$ | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=20 \mathrm{~V}, \mathrm{f}=20 \mathrm{MHz}$ | 40 | 200 | MHz |
| $\mathrm{V}_{\mathrm{BE}(\text { on })}$ | Base-Emitter On Voltage | $\mathrm{I}_{\mathrm{C}}=100 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}$ |  | 2 | V |

* Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 2 \%$


## Typical Performance Characteristics



Figure 1. DC Current Gain


Figure 3. Saturation Voltage


Figure 5. Collector CutOff Current


Figure 2. Saturation Voltage


Figure 4. Emitter Cut Off Current


Figure 6. Base-Emitter On Voltage

## Typical Performance Characteristics (Continued)



Figure 7. Output Capacitance


Figure 9. Current Gain Bandwidth Product


Figure 11. Resistive Load Switching


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